Diode Semiconductor Device - Page 1 of 1



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| In | closure Material: |
|----|---|
| М | etal |
| 0 | verall Length: |
| 0. | 350 inches |
| Т | erminal Length: |
| 0. | 900 inches |
| 0 | verall Diameter: |
| 0. | 500 inches |
| М | ounting Method: |
| Te | erminal |
| Fe | eatures Provided: |
| Н | ermetically sealed case |
| S | emiconductor Material: |
| Si | licon |
| V | oltage Rating In Volts Per Characteristic: |
| 50 | 0.0 reverse voltage, dc |
| С | urrent Rating Per Characteristic: |
| 1(| 00.00 amperes forward current, total rms watts |
| Μ | aximum Operating Tempurature Per Measurement Point: |
| 15 | 50.0 degrees celsius junction |
| Т | erminal Type And Quantity: |
| 2 | uninsulated wire lead |
| S | helf Life: |
| N | /a |
| U | nit Of Measure: |
| | |
| D | emilitarization: |
| Ν | 0 |
| Fi | ig: |
| Α | 110a0 |